

# Silicon Hyperabrupt Tuning Varactors: UHF



Bare Die    Ceramic Epoxy SMT    Glass Axial Leaded

- High Reliability, Silicon Planar
- Octave Tuning at UHF
- Octave Tuning at VHF
- Straight-Line Frequency Applications  
Over a 3 to 8 Volt Bias Range
- Low Cost Applications

The Aeroflex / Metelics UHF Tuning Varactors offer higher Qs than their VHF counterparts, but have slightly lower capacitance ratios. These diodes are excellent for octave tuning up to 800 MHz and for straight-line-frequency tuning between 3 and 8 volts of bias. They also achieve exceptionally high Q values and large signal capabilities when tuned between 9 and 20 volts, which extends their useful range to over 1 GHz. Closely matched sets are available, designed by suffix "A".

Model	Total Capacitance pF						Tuning Ratio				Q		V <sub>BR</sub>		I <sub>R</sub> nAdc					
	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	TYP	MIN	TYP	TYP	MAX	TYP	MAX	TYP	MAX
TV2101	10.5	12.5	4.3	5.7	2.0	2.3	5.0	5.8	—	—	300	350	22	30	—	—	—	—	10	100
TV2101A	10.9	12.1	4.6	5.4	2.0	2.3	5.0	5.8	—	—	300	350	22	30	—	—	—	—	10	100
TV2102	10.5	12.5	4.3	5.7	2.0	2.4	4.7	5.5	—	—	200	300	22	30	—	—	—	—	10	100
TV2102A	10.9	12.1	4.6	5.4	2.0	2.4	4.7	5.5	—	—	200	300	22	30	—	—	—	—	10	100
TV2103	10.5	12.5	4.3	5.7	—	—	—	—	1.9	2.7	200	300	15	18	—	—	50	500	—	—
TV2103A	10.9	12.1	4.6	5.4	—	—	—	—	2.0	2.6	200	300	15	18	—	—	50	500	—	—
TV2104	10.5	12.5	—	—	—	—	—	—	—	—	100	150	8	12	50	500	—	—	—	—
TV2801	25.0	31.0	10.0	13.5	4.5	5.1	5.2	6.1	—	—	200	250	22	30	—	—	—	—	20	100
TV2801A	26.5	29.5	11.0	13.0	4.5	5.1	5.2	6.1	—	—	200	250	22	30	—	—	—	—	20	100
TV2802	25.0	31.0	10.0	13.5	4.5	5.3	4.9	5.8	—	—	150	200	22	30	—	—	—	—	20	100
TV2802A	26.5	29.5	11.0	13.0	4.5	5.3	4.9	5.8	—	—	150	200	22	30	—	—	—	—	20	100
TV2803	25.0	31.0	10.0	13.5	—	—	—	—	1.9	2.8	150	200	15	18	—	—	50	500	—	—
TV2803A	26.5	29.5	11.0	13.0	—	—	—	—	2.0	2.7	150	200	15	18	—	—	50	500	—	—
TV2804	25.0	31.0	—	—	—	—	—	—	—	—	75	100	8	12	50	500	—	—	—	—
<b>Test Conds.</b>	@ -3 Vdc, F = 1 MHz		@ -8 Vdc, F = 1 MHz		@ -20 Vdc, F = 1 MHz		C <sub>T</sub> 3 / C <sub>T</sub> 20		C <sub>T</sub> 3 / C <sub>T</sub> 8		@ -3 Vdc, F = 50 MHz		@ 10 μA		@ -6 V		@ -10 V		@ -20 V	
<b>Maximum Ratings</b>	<b>Parameter</b>						<b>Value</b>													
	<b>Reverse Voltage</b>						Same as V <sub>BR</sub> (Volts)													
	<b>Forward Current</b>						100 mA													
	<b>Power Dissipation</b>						250mW													
	<b>Operating Temperature</b>						-55 to + 150 °C													
	<b>Storage Temperature</b>						-65 to + 200 °C													